

RJK0346DPA

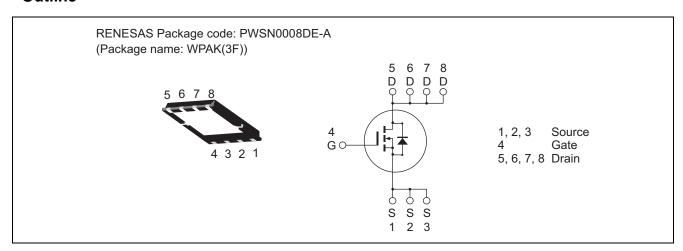
30V, 65A, $2.0m\Omega$ max. N Channel Power MOS FET High Speed Power Switching

R07DS0911EJ0400 Rev.4.00 Mar 19, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	65	Α
Drain peak current	I _{D(pulse)} Note1	260	Α
Body-drain diode reverse drain current	I _{DR}	65	Α
Avalanche current	I _{AP} Note 2	35	Α
Avalanche energy	E _{AR} Note 2	122.5	mJ
Channel dissipation	Pch Note3	65	W
Channel to Case Thermal Resistance	θch-C	1.92	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. $Tc = 25^{\circ}C$

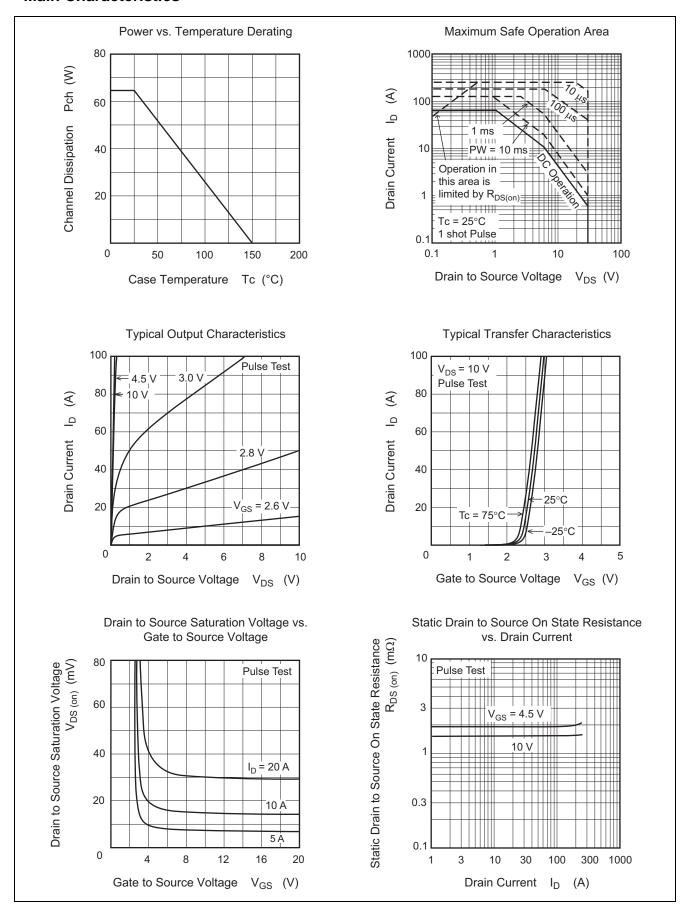
Electrical Characteristics

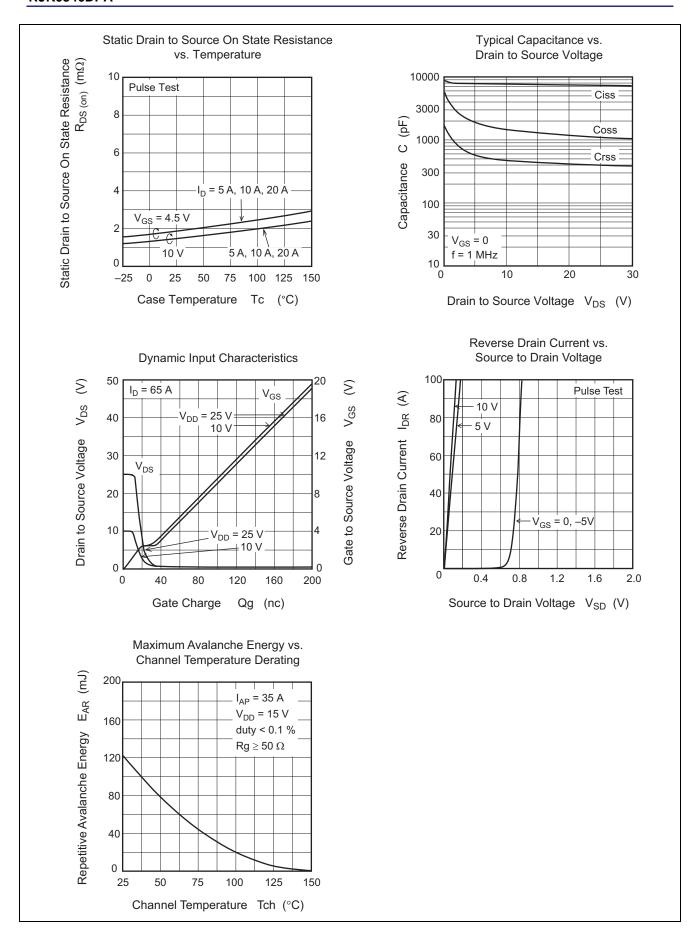
 $(Ta = 25^{\circ}C)$

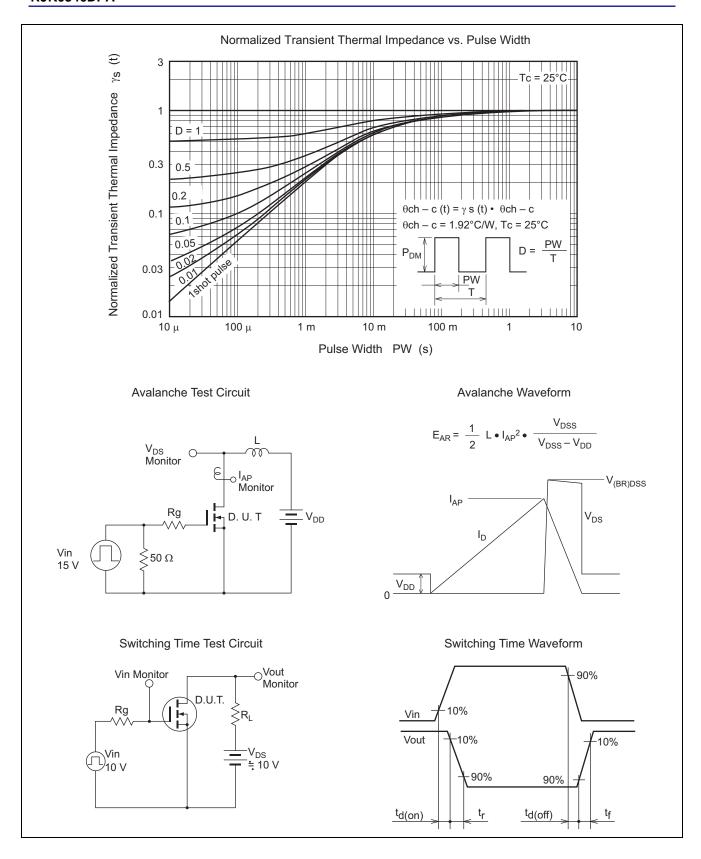
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μА	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	1.5	2.0	mΩ	$I_D = 32.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	1.9	2.7	mΩ	$I_D = 32.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	_	130	_	S	$I_D = 32.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	7650	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	1500	_	рF	f = 1 MHz
Reverse transfer capacitance	Crss	_	470	_	pF	
Gate Resistance	Rg	_	1.2	_	Ω	
Total gate charge	Qg	_	49	_	nC	$V_{DD} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 65 \text{ A}$
Gate to source charge	Qgs	_	18.7	_	nC	
Gate to drain charge	Qgd	_	10.5	_	nC	
Turn-on delay time	t _{d(on)}	_	15	_	ns	$V_{GS} = 10 \text{ V}, I_D = 32.5 \text{ A},$
Rise time	t _r	_	7	_	ns	$\begin{aligned} V_{DD} &\cong 10 \text{ V}, \text{ R}_{L} = 0.31 \Omega, \\ \text{Rg} &= 4.7 \Omega \end{aligned}$
Turn-off delay time	t _{d(off)}	_	86.5	_	ns	
Fall time	t _f	_	20	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.80	1.04	V	$I_F = 65 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	_	45	_	ns	$I_F = 65 \text{ A}, V_{GS} = 0$ $di_F / dt = 100 \text{ A} / \mu \text{s}$

Notes: 4. Pulse test

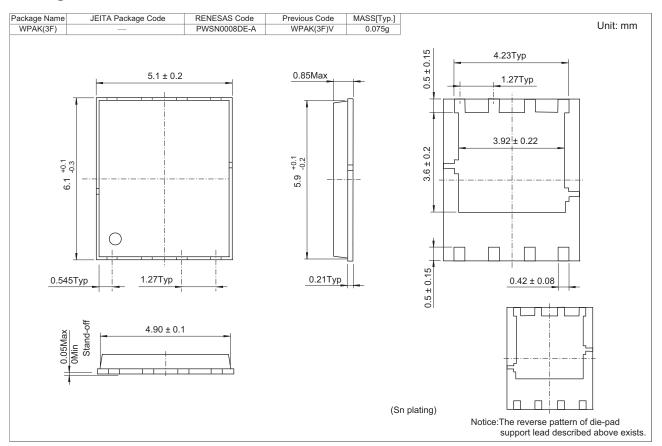
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container		
RJK0346DPA-01-J0B	2500 pcs	Taping		

Note: The symbol of 2nd "-" is occasionally presented as "#".

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